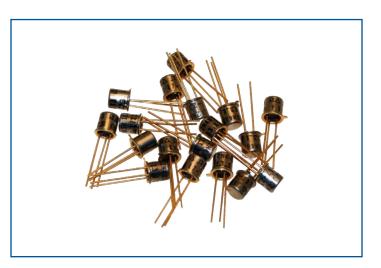


KEY FEATURES

- JAN/JANTX/JANTXV STANDARD PRODUCTS
- QUALIFIED PER MIL-PRF-19500/385
- LOW ON RESISTANCE
- FAST SWITCHING
- HIGH OFF ISOLATION
- **S LEVEL EQUIVALENT SCREENING OPTIONS**
- RADIATION TOLERANT
- SECOND SOURCE FOR VISHAY & SILICONIX



Part Number	Package	19500/	Breakdown Voltage	Current	R _{DS(on)}
2N4856	TO-18	385	40V	175mA	25 Ω
2N4857	TO-18	385	40V	100mA	4 0 Ω
2N4858	TO-18	385	40V	80mA	60 <u>Ω</u>

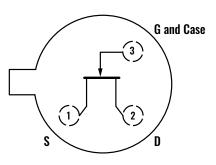
ABSOLUTE MAXIMUM RATINGS

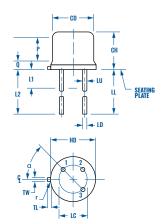
Gate-Source Voltage	-40V Storage Temperature		-65 to 200°C
Gate Current	50mA	50mA Operating Junction Temperature	
Lead Temperature (1/16 from case, 10 sec)	300°C	Power Dissipation Derating	1800mW 10.3mW/°C to TC ≥ 25°C

ORDERING GUIDE

JAN2N4856	JANTX2N4856	JANTXV2N4856
JAN2N4857	JANTX2N4857	JANTXV2N4857
JAN2N4858	JANTX2N4858	JANTXV2N4858

PACKAGE OUTLINE & PIN CONNECTIONS





	Dimensions				
Ltr	Inc	hes	mm		
	Min.	Max.	Min.	Max.	
CD	0.178	0.195	4.52	4.95	
CH	0.170	0.210	4.32	5.33	
HD	0.209	0.230	5.31	5.84	
LC	0.100 TP		2.54 TP		
LD	0.016	0.021	0.41	0.53	
LL	0.500	0.750	2.70	19.05	
LU	0.016	0.019	0.41	0.48	
L1		0.050		1.27	
L2	0.250		6.35		
Р	0.100		2.54		
Q		0.030		0.76	
TL	0.028	0.048	0.71	1.22	
TW	0.036	0.046	0.91	1.17	
r		0.010		0.25	
α	45° TP				



ELECTRICAL SPECIFICATIONS

Typical @ 25°C unless otherwise noted

Parameter	Symbol	Min.	Max.	Unit
Gate-Source Breakdown Voltage V _{DS} =OVdc, I _G = 1.0Adc	V _{(BR)GSS}	-40		Vdc
Gate-Source "Off" State Voltage V _{DS} = 15Vdc, I _D = 0.5nAdc 2N4856 2N4857 2N4858	$V_{GS(on)}$	-4 -2 -0.8	-10 -6 -4	Vdc Vdc Vdc
Gate Reverse Current $V_{DS} = 0Vdc, V_{GS} = -20Vdc$ $V_{DS} = 0Vdc, V_{GS} = -15Vdc$	I _{GSS}		-0.25 -0.25	nA nA
	_{D(off)}	50 20 8	0.25 175 100 80	nA mA mA mA
Static Drain - Source "On" State Resistance V_{GS} = 0Vdc, I_{D} = 1mAdc2N48562N48572N4858	R _{DS(on)}		25 40 60	Ω Ω Ω
$\label{eq:scalar} \begin{array}{llllllllllllllllllllllllllllllllllll$	V _{DS(on)}		0.75 0.5 0.5	Vdc Vdc Vdc
Small Signal, Common Source Reverse Transfer Capacitance $V_{_{GS}}$ = -10Vdc $V_{_{DS}}$, $V_{_{D}}$ = 0Vdc, f = 1.0MHz C_1 = 0.1µF, L1 =L2 ≥ 500µH	C _{rss}		8	pF
Small Signal, Common Source Short-Circuit Input Capacitance $V_{_{GS}}$ = -10Vdc $V_{_{DS'}}$ VD = 0Vdc, f = 1.0MHz C_1 = 0.1µF, C2 = 20.1m $F_{_{L1}}$ = $L_2 \ge 500\mu$ H	C _{iss}		8	pF
Turn On Delay Time 2N4856 2N4857 2N4858	t _{D(on)}		6 6 10	nS nS nS
Rise Time 2N4856 2N4857 2N4858	ţ,		3 4 10	nS nS nS
Turn Off Delay Time 2N4856 2N4857 2N4858	t _{d(off)}		25 50 100	nS nS nS

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